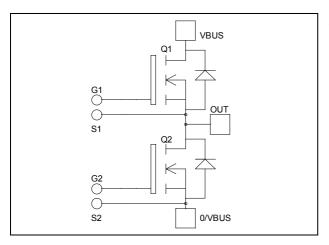
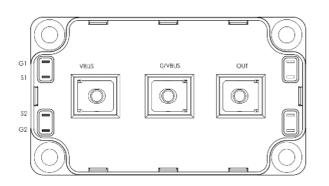


### Phase leg MOSFET Power Module





### $V_{DSS} = 1000V$ $R_{DSon} = 90m\Omega \text{ typ } @ \text{ Tj} = 25^{\circ}\text{C}$ $I_D = 78\text{A} @ \text{Tc} = 25^{\circ}\text{C}$

#### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### Features

- Power MOS 7<sup>®</sup> FREDFETs
  - Low R<sub>DSon</sub>
    - Low input and Miller capacitance
    - Low gate charge
    - Fast intrinsic reverse diode
    - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

#### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>DSS</sub>	Drain - Source Breakdown Voltage		1000	V
I <sub>D</sub>	Continuous Drain Current	$T_c = 25^{\circ}C$	78	
Б		$T_c = 80^{\circ}C$	59	А
I <sub>DM</sub>	Pulsed Drain current		312	
V <sub>GS</sub>	Gate - Source Voltage		$\pm 30$	V
R <sub>DSon</sub>	Drain - Source ON Resistance		105	mΩ
PD	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1250	W
I <sub>AR</sub>	Avalanche current (repetitive and non repetitive)		25	А
E <sub>AR</sub>	Repetitive Avalanche Energy		50	mJ
E <sub>AS</sub>	Single Pulse Avalanche Energy		3000	IIIJ

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25^{\circ}C$			400	A	
		$V_{GS} = 0V, V_{DS} = 800V$	$T_{j} = 125^{\circ}C$			2000	μA	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 39A$			90	105	mΩ	
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10 \text{mA}$		3		5	V	
I <sub>GSS</sub>	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±250	nA	

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	Input Capacitance	$V_{GS} = 0V$		20.7		
C <sub>oss</sub>	Output Capacitance	$V_{\rm DS} = 25 V$		3.5		nF
C <sub>rss</sub>	Reverse Transfer Capacitance	f=1MHz		0.64		
Qg	Total gate Charge	$V_{GS} = 10V$		744		nC
Q <sub>gs</sub>	Gate – Source Charge	$V_{Bus} = 500V$		96		
$Q_{gd}$	Gate – Drain Charge	$I_D = 78A$		488		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 670V$ $I_D = 78A$ $R_G = 1.2\Omega$		18		ns
T <sub>r</sub>	Rise Time			12		
T <sub>d(off)</sub>	Turn-off Delay Time			155		
$T_{\rm f}$	Fall Time			40		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$ , $V_{Bus} = 670V$ $I_D = 78A$ , $R_G = 1.2\Omega$		3.6		T
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			2.5		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 78A, R_G = 1.2\Omega$		5.7		I
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			3.1		mJ

### **Source - Drain diode ratings and characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Is	Continuous Source current		$Tc = 25^{\circ}C$			78	А
	(Body diode)		$Tc = 80^{\circ}C$			59	Λ
V <sub>SD</sub>	Diode Forward Voltage	$V_{GS} = 0V, I_S = -78A$				1.3	V
dv/dt	Peak Diode Recovery <b>1</b>					18	V/ns
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25^{\circ}C$			320	ns
		$I_{S} = -78A$ $V_{R} = 670V$	$T_j = 125^{\circ}C$			650	115
Q <sub>rr</sub>	Reverse Recovery Charge	$di_{\rm S}/dt = 400 {\rm A}/{\rm \mu s}$	$T_j = 25^{\circ}C$		14.4		μC
	Reverse Receivery Charge		$T_{i} = 125^{\circ}C$		38.9		μυ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

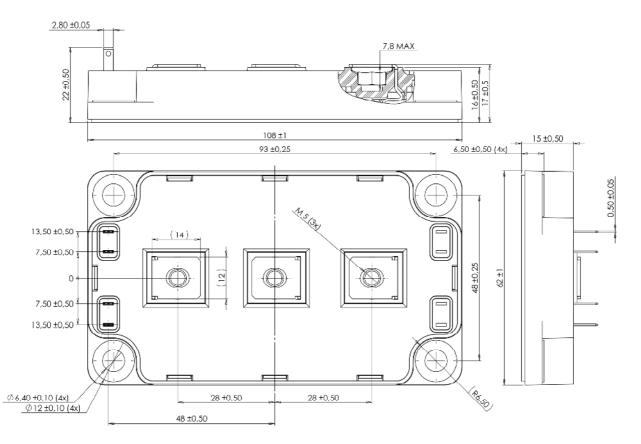
$$I_{S} \leq -78A \qquad di/dt \leq 700 A/\mu s \qquad V_{R} \leq V_{DSS} \qquad T_{j} \leq 150^{\circ}C$$



### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.1	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range			-40		150	°C
T <sub>STG</sub>	Storage Temperature Range			-40		125	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

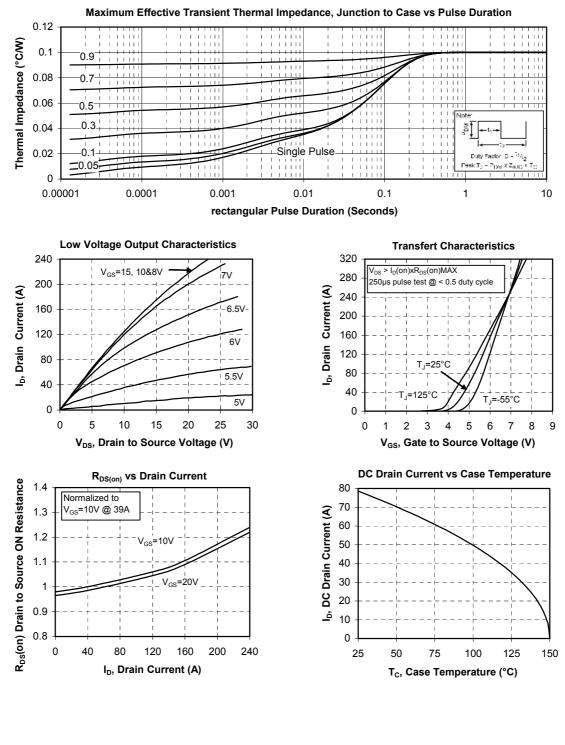
#### SP6 Package outline (dimensions in mm)



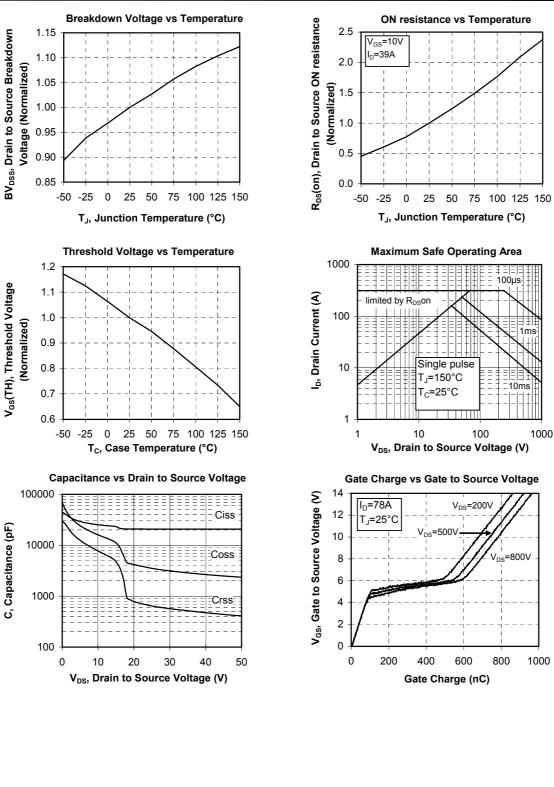
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com



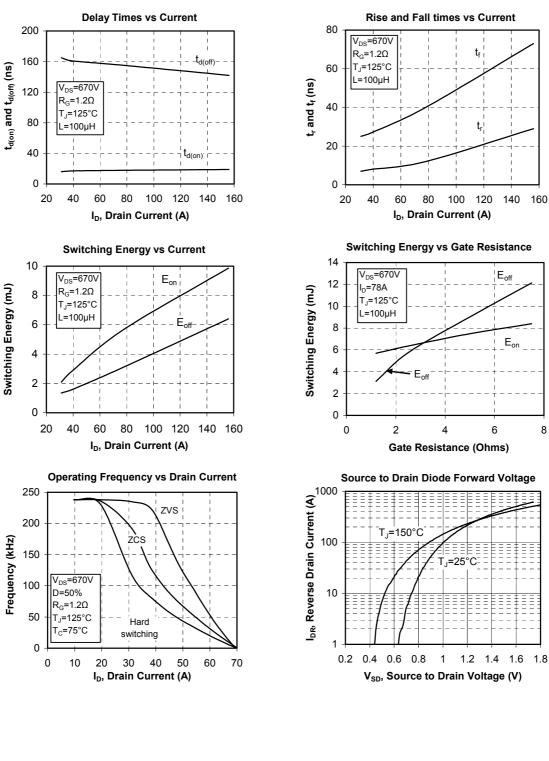
### **Typical Performance Curve**











APTM100AM90FG- Rev 3 October, 2012



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